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SGA-0363(Z)

DC to 5000 MHz, SILICON GERMANIUM CASCADABLE GAIN BLOCK

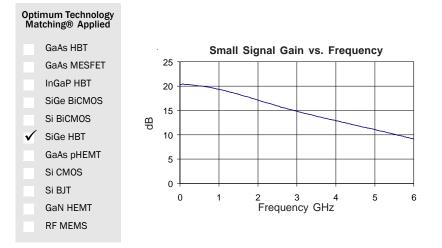


RFM

RFMD Green, RoHS Compliant, Pb-Free (Z Part Number) Package: SOT-363

Product Description

The SGA-0363 is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high FT and excellent thermal perfomance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor and an optional RF choke are required for operation.



Features

- DC to 5000MHz Operation
- Single Voltage Supply
- Low Current Draw: 11mA at 2.5V Typ.
- High Output Intercept: 14dBm Typ. at 1950MHz

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

Parameter	Specification			Unit	Oandition	
Parameter	Min.	Тур.	Max.	Unit	Condition	
Output Power at 1dB Compression		2.3		dBm	850MHz	
		2.3		dBm	1950MHz	
		1.6		dBm	2400MHz	
Third Order Intercept Point		14.2		dBm	850MHz	
		14.0		dBm	1950MHz	
		13.1		dBm	2400MHz	
Small Signal Gain		19.6		dB	850MHz	
		17.2		dB	1950MHz	
		16.2		dB	2400MHz	
3dB Bandwidth		5000		MHz		
Input VSWR		1.8:1			DC to 4500MHz	
Output VSWR		1.7:1			DC to 4500MHz	
Reverse Isolation		24.0		dB	850MHz	
		22.8		dB	1950MHz	
		22.1		dB	2400MHz	
Noise Figure ^[1]		3.0		dB	1950MHz	
Device Operating Voltage		2.5		V		
Device Operating Current	9	11	13	mA		
Thermal Resistance		255		°C/W	junction - lead	
Thermal Resistance	T -25°C (1 MHz B. p.	,	5	

Test Conditions: V_S=5V, I_D=11mA Typ., T_L=25 °C. OIP3 Tone Spacing=1MHz, P_{OUT} per tone=-12 dBm, R_{BIAS}=220 Ω , Z_S=Z_L=50 Ω

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Prelim DS090924

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Absolute Maximum Ratings

Parameter	Rating	Unit
Device Current (I _D)	22	mA
Device Voltage (V _D)	6	V
RF Input Power	-5	dBm
Junction Temp (T _J)	+150	°C
Operating Temp Range (T _L)	-40 to +85	°C
Storage Temp	+150	°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression: $I_DV_D < (T_J - T_L)/R_{TH}$, j-l

Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating condi-tions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

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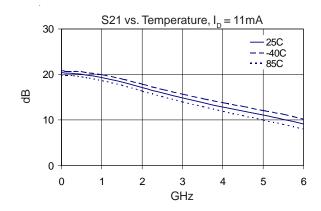
Developedation	Specification			11	0 <u>1</u> 't'	
Parameter	Min.	Тур.	Max.	Unit	Condition	
Gain		20.4		dB	100MHz	
		20.0		dB	500MHz	
		19.6		dB	850MHz	
		17.2		dB	1950MHz	
		16.2		dB	2400MHz	
		13.8		dB	3500MHz	
Output IP ₃		14.8		dBm	100MHz, Tone spacing=1MHz, P _{OUT} per tone= -12dBm	
		14.5		dBm	500MHz, Tone spacing=1MHz, P _{OUT} per tone= -12dBm	
		14.2		dBm	850MHz, Tone spacing=1MHz, P _{OUT} per tone= -12dBm	
		14.0		dBm	1950MHz, Tone spacing=1MHz, P _{OUT} per tone= -12dBm	
		13.1		dBm	2400MHz, Tone spacing=1MHz, P _{OUT} per tone= -12dBm	
		11.5		dBm	3500MHz, Tone spacing=1MHz, P _{OUT} per tone= -12dBm	
Output P1dB		3.2		dBm	100MHz	
		2.9		dBm	500MHz	
		2.3		dBm	850MHz	
		2.3		dBm	1950MHz	
		1.6		dBm	2400MHz	
		0.8		dBm	3500MHz	
Input Return Loss		9.3		dB	100MHz	
		9.4		dB	500MHz	
		9.4		dB	850MHz	
		10.4		dB	1950MHz	
		10.8		dB	2400MHz	
		11.3		dB	3500MHz	
Reverse Isolation		23.9		dB	100MHz	
		23.9		dB	500MHz	
		24.0		dB	850MHz	
		22.8		dB	1950MHz	
		22.1		dB	2400MHz	
		20.1		dB	3500MHz	
Noise Figure		2.9		dB	100MHz, Z _S =50Ω	
		2.8		dB	500MHz, Z _S =50Ω	
		3.0		dB	850MHz, Z _S =50Ω	
	-	3.0		dB	1950MHz, Z _S =50Ω	

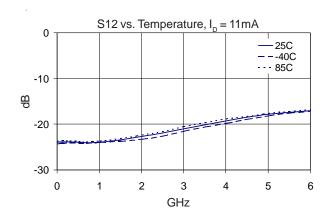
Test Conditions: ID=8mA, unless otherwise noted

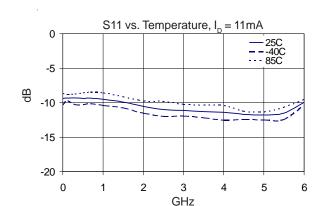


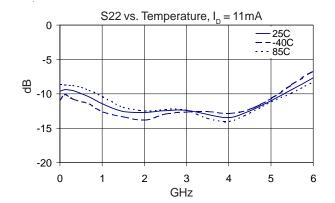
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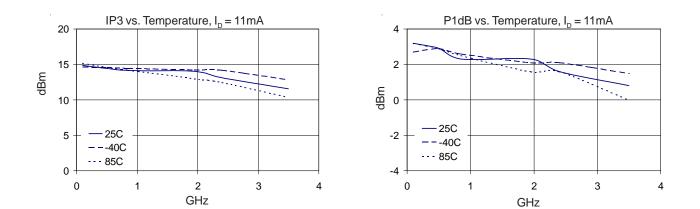
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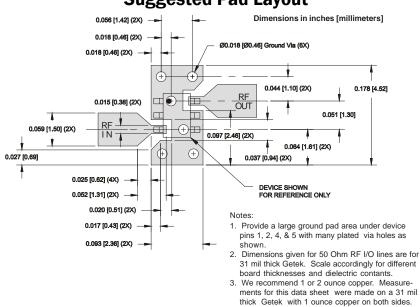
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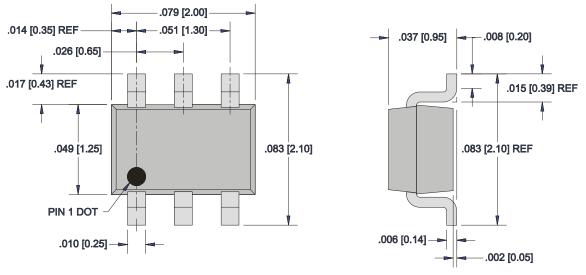
Pin	Function	Description
3	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
1, 2,	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
4, 5		
6	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper oper- ation.



Suggested Pad Layout



Dimensions in inches (millimeters) Refer to drawing posted at www.rfmd.com for tolerances.

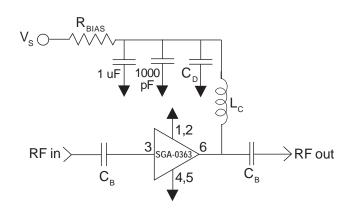


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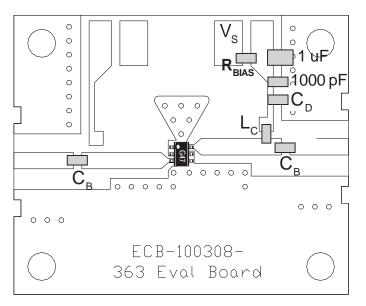
Application Schematic



Reference	Frequency (Mhz)				
Designator	500	850	1950	2400	3500
C _B	220 pF	100 pF	68 pF	56 pF	39 pF
C _D	100 pF	68 pF	22 pF	22 pF	15 pF
L _c	68 nH	33 nH	22 nH	18 nH	15 nH

Recommended Bias Resistor Values for I_{D} =11mA R_{BIAS} =(V_{S} - V_{D}) / I_{D}					
Supply Voltage(V _s)	5 V	7.5 V	9 V	12 V	
R _{BIAS} 220 Ω 470 Ω 620 Ω 910 Ω					
Note: R _{BIAS} provides DC bias stability over temperature.					

Evaluation Board Layout



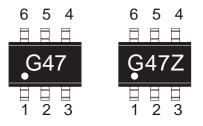
Mounting Instructions

- Use a large ground pad area near device pins 1, 2,
 4, and 5 with many plated through-holes as shown.
- 2. We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

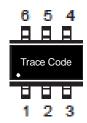




Part Identification Marking



Alternate Marking with Trace Code Only



Ordering Information

Part Number	Reel Size	Devices/Reel	
SGA-0363	7"	3000	
SGA-0363Z	7"	3000	

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